

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,762,450 B2
DATED : July 13, 2004
INVENTOR(S) : Gurtej Sandhu et al.

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Title page.

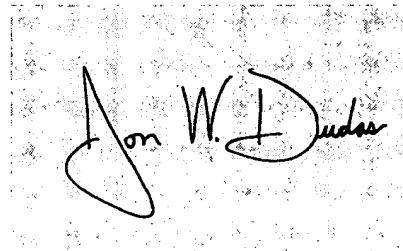
Item [56], References Cited, OTHER PUBLICATIONS, in the "Institute of Semiconductor Physics" reference, please delete "Temmter, D" before "Multilayer Vertical" and insert Temmler, D., --, in the "University of California" reference, please delete "Nierdef, H.," before "Organometallic Chemical" and insert -- Niemer, H., --, in the "IEDM" reference, please delete "H. Wannabe et al.," before "Stacked Capacitor" and insert -- H. Watanabe et al., --.

Column 5.

Line 56, please delete "is" after "layer 34".

Signed and Sealed this

Seventh Day of June, 2005



JON W. DUDAS
Director of the United States Patent and Trademark Office